NSN 5961-01-006-0985

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-006-0985 **Inclosure Material:** Plastic **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 collector to base voltage/static/emitter open 3rd transistor and 35.0 collector to emitter voltage/static/base open 3rd transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current 3rd transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No